

Descriptions

This 30V 74A is N-Channel Enhancement Mode Field Effect Transistor in a PDFN3×3A-8L Plastic Package.

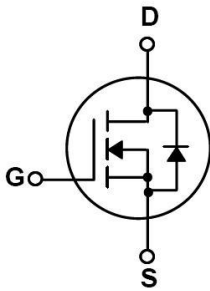
Features

- VDS (V) = 30V
- ID =74A (VGS =±20V)
- RDS(ON)@10V≤3.7mR(Typ.3.5mR)
- RDS(ON)@4.5V≤6.5mR(Typ.4.5mR)
- Halogen-free Product

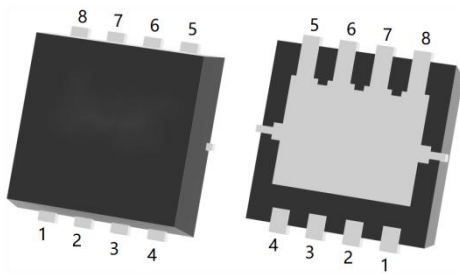
Applications

- Load Switch Applications
- Battery Power Management

Equivalent Circuit



Pinning



出脚	定义
Pin1	S
Pin2	S
Pin3	S
Pin4	G
Pin5	D
Pin6	D
Pin7	D
Pin8	D

Marking

See Marking Instructions.

Absolute Maximum Ratings(Ta=25°C)

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V _{DSS}	30	V
Drain Current		I _D (T _C =25°C)	74	A
Drain Current - Pulsed		I _{DM}	185	A
Gate-Source Voltage		V _{GSS}	±20	V
Single Pulsed Avalanche Energy		E _{AS}	449	mJ
Avalanche Current		I _{AS}	33.5	A
Power Dissipation		P _D (T _C =25°C)	35	W
Operating and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C
Junction-to-Ambient	t ≤ 10	R _{θJA}	42	°C/W
Junction-to-Ambient	Steady-State		78	
Junction-to-Case	Steady-State		3.6	

Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V	I _D =250μA	30	35		V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V	V _{GS} =0V			1	μA
Gate-Body Leakage Current Forward	I _{GSS}	V _{GS} =±20V	V _{DS} =0V			±0.1	μA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS}	I _D =250μA	1.0	1.5	3.0	V
Static Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V	I _D =20A		3.5	3.7	mΩ
		V _{GS} =4.5V	I _D =10A		4.5	6.5	mΩ
Drain-Source Diode Forward Voltage	V _{SD}	V _{GS} =0V	I _S =1A			1.2	V
Input Capacitance	C _{iSS}	V _{DS} =25V f=1.0MHz	V _{GS} =0V		2750		pF
Output Capacitance	C _{oss}				380		
Reverse Transfer Capacitance	C _{rss}				240		
Gate resistance	R _g	V _{GS} =0V f=1MHz	V _{DS} =0V		2.6		Ω
Total Gate Charge	Q _{g(10V)}	V _{GS} =10V I _D =20A	V _{DS} =15V		80		nC
Total Gate Charge	Q _{g(4.5V)}				35		
Gate Source Charge	Q _{gs}				13		
Gate Drain Charge	Q _{gd}				13		
Turn-On Delay Time	t _{d(on)}	V _{GS} =10V R _L =0.75Ω	V _{DS} =15V R _{GEN} =3.0Ω		6.7		ns
Turn-On Rise Time	t _r				3.8		
Turn-Off Delay Time	t _{d(off)}				32		
Turn-Off Fall Time	t _f				5.2		

Electrical Characteristic Curve

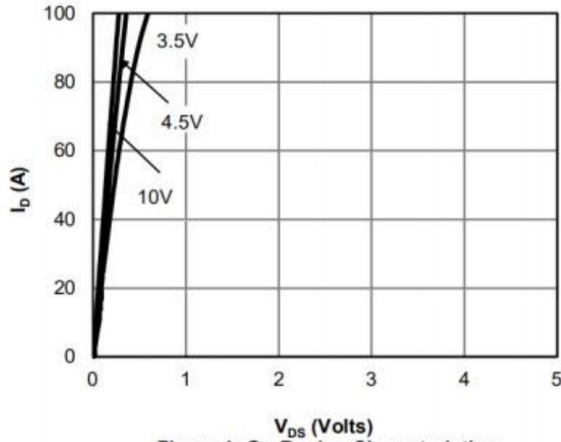


Figure 1: On-Region Characteristics

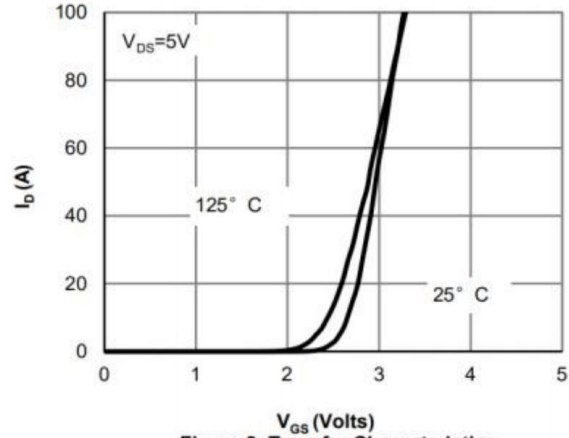


Figure 2: Transfer Characteristics

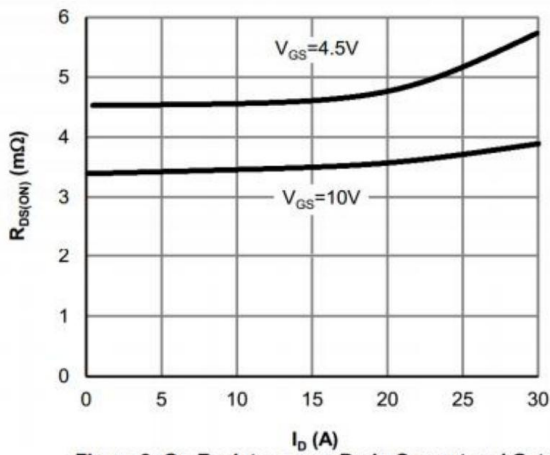


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

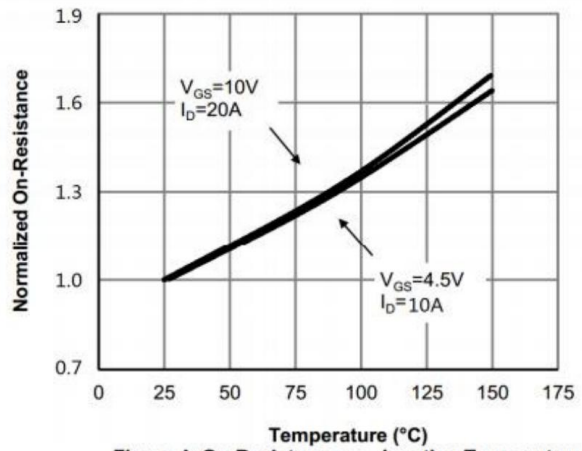


Figure 4: On-Resistance vs. Junction Temperature

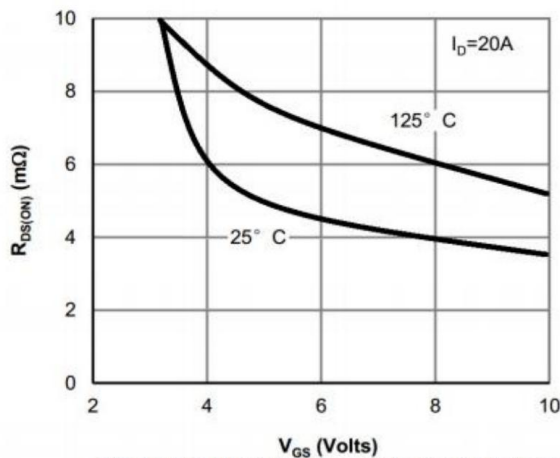


Figure 5: On-Resistance vs. Gate-Source Voltage

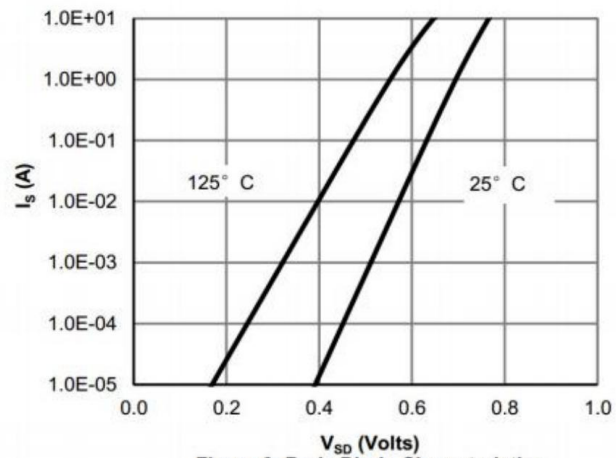


Figure 6: Body-Diode Characteristics

Electrical Characteristic Curve

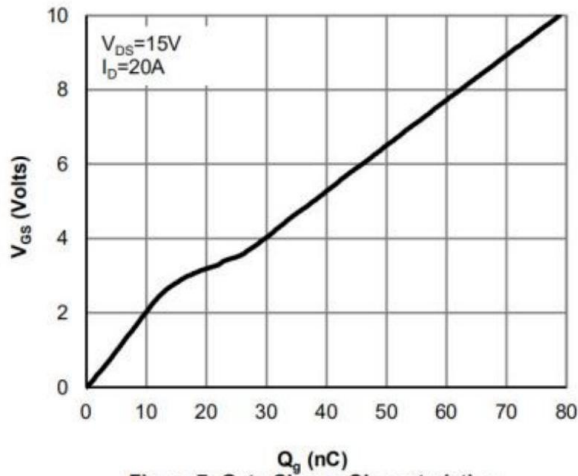


Figure 7: Gate-Charge Characteristics

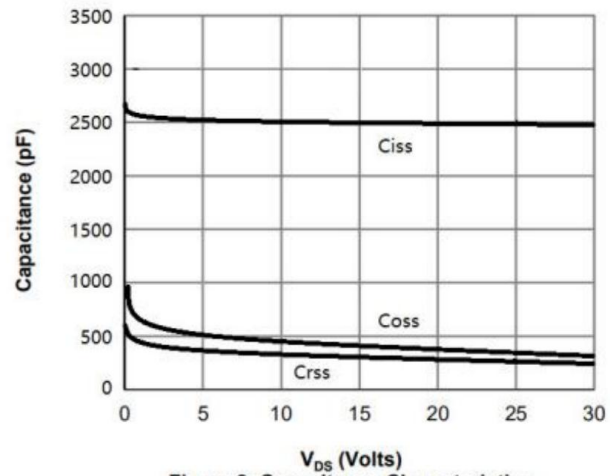


Figure 8: Capacitance Characteristics

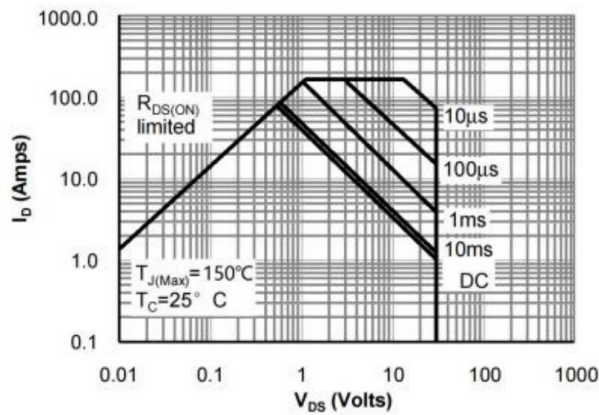


Figure 9: Maximum Forward Biased Safe Operating Area

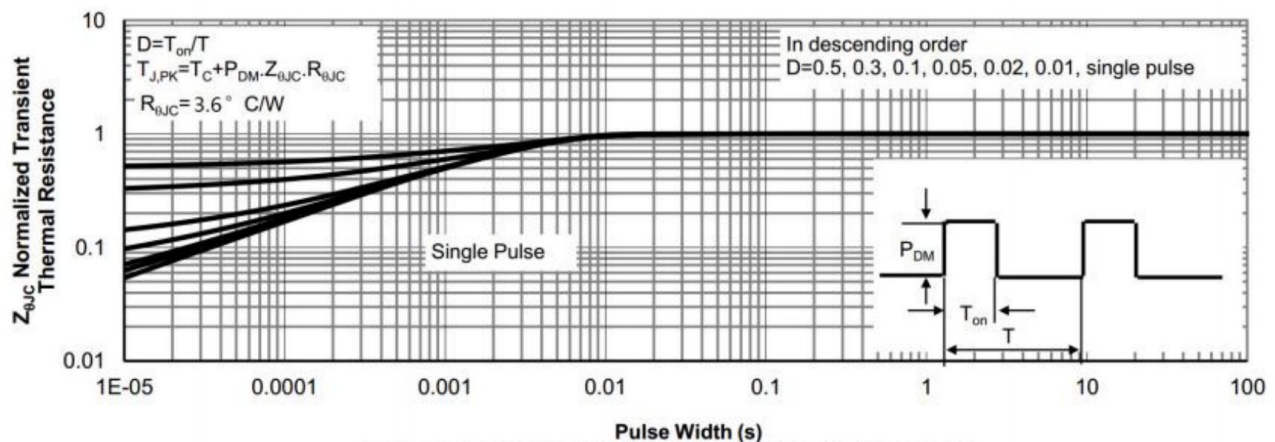
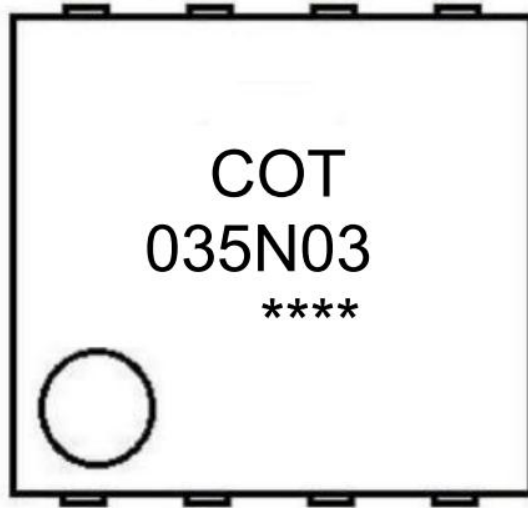


Figure 10: Normalized Maximum Transient Thermal Impedance

Marking Instructions



- Note:
- COT: Company Logo
 - 035N03: Product Type.
 - ****: Lot No. Code, code change with Lot No.

Packaging SPEC

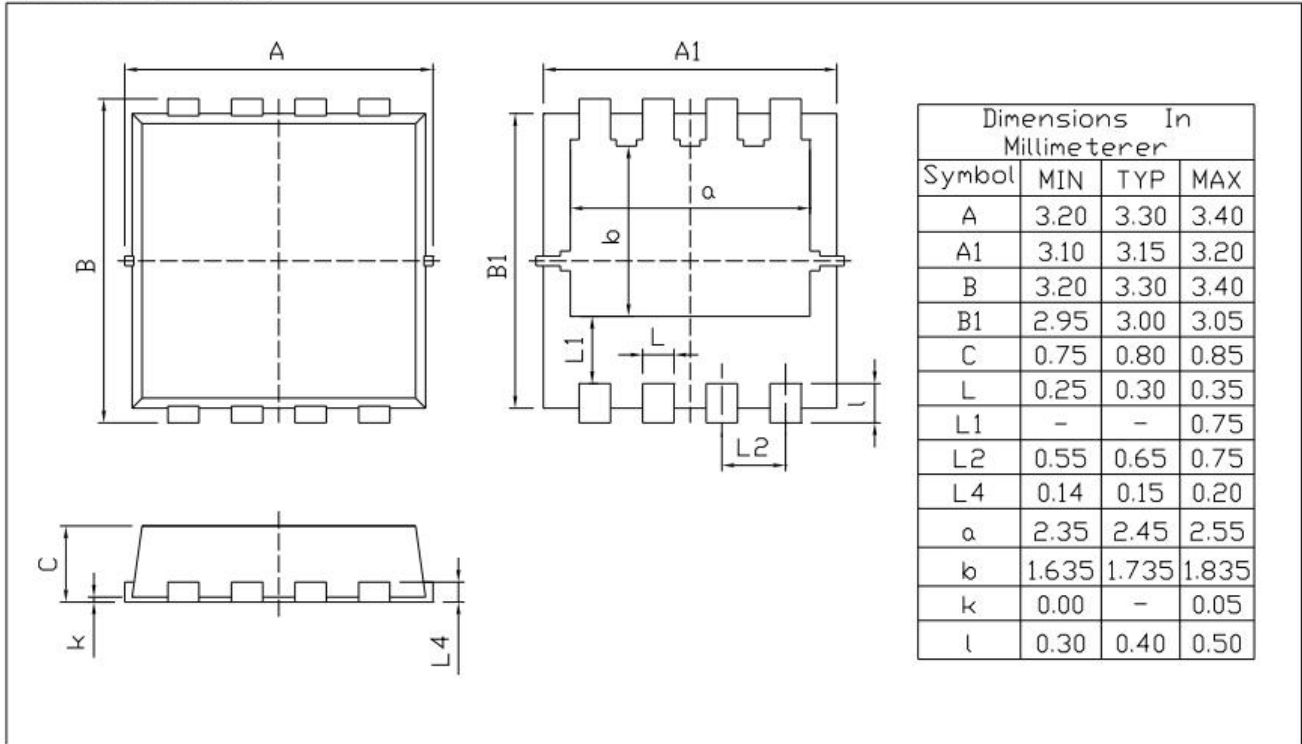
REEL INFORMATION

Package Type	Units					Dimension (unit: mm ³)		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
PDFN3×3A-8L	5,000	2	10,000	6	60,000	13" ×12	360×360×50	380×335×366

Package Outline Dimensions

PDFN3X3A-8L

Unit:mm



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